

 	EPC2012
	Manufacturer Part Number: EPC2012
	Manufacturer/Brand: EPC
	Part of Description: TRANS GAN 200V 3A BUMPED DIE
	Datasheets:  EPC2012.pdf
	RoHs Status:  Lead free / RoHS
	Stock Condition: Compliant New original, 2586 pcs Stock Available.
	Ship From: Hong Kong
Image may be representation. See specs for product details.	Shipment Way: DHL/Fedex/TNT/UPS/EMS

Specifications	
Part Number	EPC2012
Manufacturer	EPC
Description	TRANS GAN 200V 3A BUMPED DIE
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2586 pcs Stock
Vgs(th) (Max) @ Id	2.5V @ 1mA
Technology	GaNFET (Gallium Nitride)
Supplier Device Package	Die
Series	eGaN®
Rds On (Max) @ Id, Vgs	100 mOhm @ 3A, 5V
Power Dissipation (Max)	-
Packaging	Cut Tape (CT)
Package / Case	Die
Operating Temperature	-40°C ~ 125°C (TJ)
Mounting Type	Surface Mount
Input Capacitance (Ciss) (Max) @ Vds	145pF @ 100V
Gate Charge (Qg) (Max) @ Vgs	1.8nC @ 5V
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	3A (Ta)

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